

# 8A, 100V - 200V Ultra Fast Surface Mount Rectifier

#### **FEATURES**

- AEC-Q101 qualified
- Planar technology
- Low power loss, high efficiency
- Ideal for automated placement
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free

#### **APPLICATIONS**

- High frequency switching
- DC/DC
- Snubber

#### **MECHANICAL DATA**

Case: ThinDPAK

• Molding compound meets UL 94V-0 flammability rating

• Terminal: Matte tin plated leads, solderable per J-STD-002

Meet JESD 201 class 2 whisker test

• Polarity: Indicated by cathode band

• Weight: 0.193g (approximately)

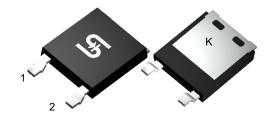
KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
l <sub>F</sub>	8	Α	
$V_{RRM}$	100 - 200	V	
I <sub>FSM</sub>	150	Α	
T <sub>J MAX</sub>	175	°C	
Package	ThinDPAK		
Configuration	Single die		



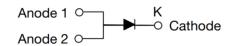








**ThinDPAK** 



PARAMETER		SYMBOL	PUAD8BH	PUAD8DH	UNIT
Marking code on the device			UAD8B	UAD8D	
Repetitive peak reverse voltage		V <sub>RRM</sub>	100	200	V
Reverse voltage, total rms value		V <sub>R(RMS)</sub>	70	140	V
Forward current		l <sub>F</sub>	8		А
Surge peak forward current single half sine-wave superimposed on rated load	t = 8.3ms	,	150		
	t = 1.0ms	- I <sub>FSM</sub>	30	00	A
Junction temperature		TJ	-55 to +175		°C
Storage temperature		T <sub>STG</sub>	-55 to +175		°C

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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-lead thermal resistance	R <sub>OJL</sub>	3.5	°C/W
Junction-to-ambient thermal resistance	Reja	11.8	°C/W
Junction-to-case thermal resistance	Rejc	2.0	°C/W

Thermal Performance Note: Mounted on heat sink with 2" x 3" x 0.25" Al-Plate

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
	I <sub>F</sub> = 4A, T <sub>J</sub> = 25°C		0.84	-	V
Forward voltage <sup>(1)</sup>	I <sub>F</sub> = 4A, T <sub>J</sub> = 125°C	V	0.68	-	V
	I <sub>F</sub> = 8A, T <sub>J</sub> = 25°C	VF	0.92	1.00	V
	I <sub>F</sub> = 8A, T <sub>J</sub> = 125°C		0.77	-	V
Doverse surrent @ reted 1/-(2)	T <sub>J</sub> = 25°C	- I <sub>R</sub>	-	2	μΑ
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>	T <sub>J</sub> = 125°C		4	-	μA
Junction capacitance	1MHz, V <sub>R</sub> = 4.0V	Сл	101	-	pF
Doverse recovery time	I <sub>F</sub> = 0.5A, I <sub>R</sub> = 1.0A, I <sub>rr</sub> = 0.25A	4	-	25	ns
Reverse recovery time	$I_F = 1.0A$ , $di/dt = 50A/\mu s$ , $V_R = 30V$	t <sub>rr</sub>	23	-	
Reverse recovery current		I <sub>RM</sub>	2.4	-	Α
Reverse recovery charge	$I_F = 8.0A$ , di/dt = 200A/ $\mu$ s, $V_R = 100V$	Qrr	35	-	nC
Reverse recovery time		t <sub>rr</sub>	19	-	ns

# Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE(1)	PACKAGE	PACKING	
PUAD8xH	ThinDPAK	4,500 / Tape & Reel	

# Notes:

1. "x" defines voltage from 100V(PUAD8BH) to 200V(PUAD8DH)



# **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

**Fig.1 Forward Current Derating Curve** 

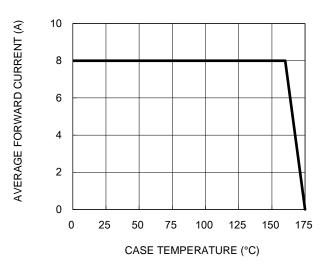


Fig.3 Typical Reverse Characteristics

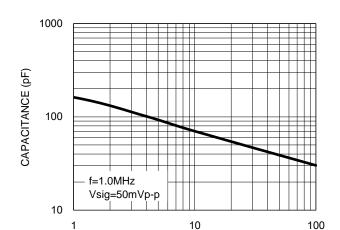
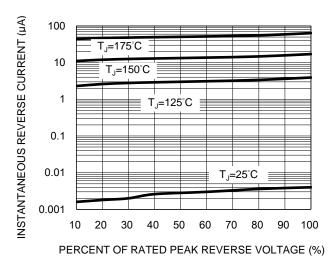


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics

REVERSE VOLTAGE (V)



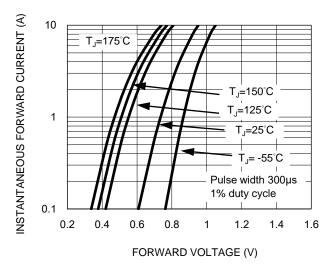
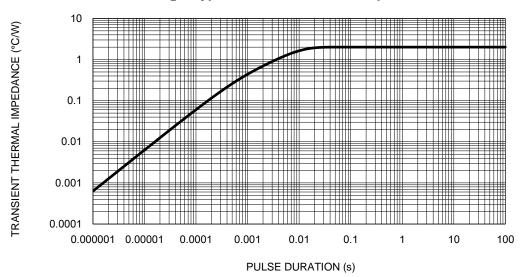


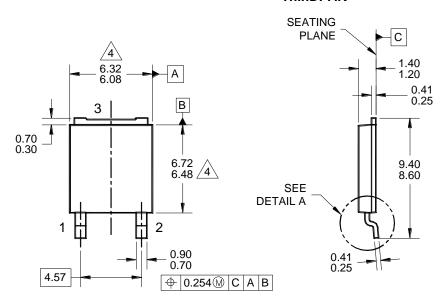
Fig.5 Typical Transient Thermal Impedance

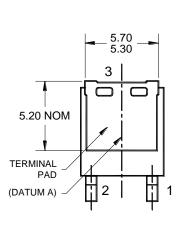


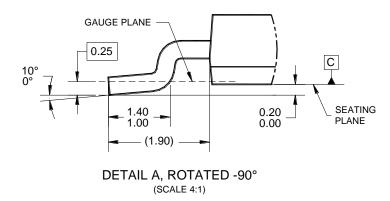


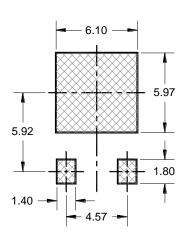
# **PACKAGE OUTLINE DIMENSIONS**

#### **ThinDPAK**

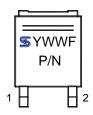








SUGGESTED PAD LAYOUT



# MARKING DIAGRAM

YWW = DATE CODE F = FACTORY CODE P/N = MARKING CODE NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. PACKAGE OUTLINE REFERENCE: JEDEC TO-252, VARIATION AE, ISSUE F.
- MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSION, OR GATE BURRS.
  - 5. DWG NO. REF: HQ2SD07-TDPAK-065 REV A.



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